Brückewell Bruckewell Technology Corp., Ltd.

http://www.bruckewell-semicon.com/ N-Channel 30-V (D-S) MOSFET

MSC22N03

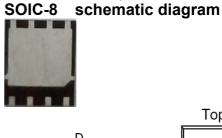
These miniature surface mount MOSFETs utilize a high cell density trench process to provide low RDS(on) and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, and PCMCIA cards, cellular and cordless telephones.

Key Features:

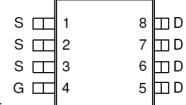
- •Low rDS(on) provides higher efficiency and extends battery life
- •Low thermal impedance copper lead frame SOIC-8 saves board space

•Fast switching speed

• High performance trench technology



Top View



N-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED) | | | | | | | |
|--|--|----------------|------------|----|--|--|--|
| Parame te r | Symbol | Maximum | Units | | | | |
| Drain-Source Voltage | | | 30 | v | | | |
| Gate-Source Voltage | | | 20 | v | | | |
| | T _A =25°C | т | 22 | | | | |
| Continuous Drain Current ^a | T _A =25°C T _A =70°C | ID | 18 | А | | | |
| Pulsed Drain Current ^b | I _{DM} | 50 | | | | | |
| Continuous Source Current (Diode Conduction) ^a | | Is | 2.3 | А | | | |
| | T _A =25°C | р | 5 | w | | | |
| Power Dissipation ^a | T _A =25°C T _A =70°C | Р _D | 2.2 | vv | | | |
| Operating Junction and Storage Temperature Range | - | TJ, Tstg | -55 to 150 | °C | | | |

| THERMAL RESISTANCE RATINGS | | | | | | |
|--|--------------|------------------|---------|------|--|--|
| Parameter | Symbol | Maximum | 1 Units | | | |
| a a a a a a | t <= 10 sec | р | 25 | °C/W | | |
| Maximum Junction-to-Ambient ^a | Steady State | R _{0JA} | 65 | °C/W | | |

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

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| SPECIFICATIONS ($T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED) | | | | | | | |
|--|---------------------|---|--------|-----|-----|------|--|
| Parame te r | Complex 1 | | Limits | | | TI | |
| | Symbol | Test Conditions | Min | Тур | Max | Unit | |
| Static | | | | | | | |
| Gate-Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$ | 1 | | | V | |
| Gate-Body Leakage | Igss | $V_{DS} = 0 V, V_{GS} = 20 V$ | | | 100 | nA | |
| Zara Cata Valtara Drain Current | I | $V_{DS} = 24 V, V_{GS} = 0 V$ | | | 1 | | |
| Zero Gate Voltage Drain Current | I _{DSS} | $V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$ | | | 5 | uA | |
| On-State Drain Current ^A | ID(on) | $V_{DS} = 5 V, V_{GS} = 10 V$ | 40 | | | А | |
| Dia o Dia A | IDS(on) | $V_{GS} = 10 \text{ V}, I_D = 2 \text{ A}$ | | | 7.5 | | |
| Drain-Source On-Resistance ^A | | $V_{GS} = 4.5 V$, $I_D = 2 A$ | | 11. | | mΩ | |
| Forward Tranconductance ^A | gńs | VDS = 15 V, ID = 2 A | | 40 | | S | |
| Diode Forward Voltage | Vsd | $I_S = 2 A, V_{GS} = 0 V$ | | 0.7 | | V | |
| Dynamic ^b | | | | | | | |
| Total Gate Charge | Qg | Ver 15 V Ver 45 V | | 16 | | nC | |
| Gate-Source Charge | Qgs | $V_{DS} = 15 V$, $V_{GS} = 4.5 V$, $I_D = 10 A$ | | 5 | | | |
| Gate-Drain Charge | Qgd | ID = 10 A | | 6 | | | |
| Turn-On Delay Time | t _{d(on)} | | | 5 | | | |
| Rise Time | tr | V_{DD} = 15 V, R_L = 6 Ω , ID = 1 A, | | 4 | | nS | |
| Turn-Off De lay Time | t _{d(off)} | VGEN = 10 V | | 23 | | | |
| Fall-Time | tf | | | 9 | | | |

Notes

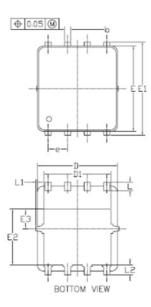
a. Pulse test: PW <= 300us duty cycle <= 2%.

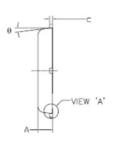
b. Guaranteed by design, not subject to production testing.

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Package Information •







VIEW 'A' (SCALE 5:1)

| SYMBOLS | DIMENSIONS IN MILLIMETERS | | | DIMENSIONS IN INCHES | | | |
|---------|---------------------------|---------------------|-----------|----------------------|---------------|-------|--|
| STMBOLS | MIN | NOM | MAX | MIN | NOM | MAX | |
| Α | 0.85 | 0.95 | 1.00 | 0.033 | 0.037 | 0.039 | |
| A1 | 0.00 | | 0.05 | 0.000 | | 0.002 | |
| b | 0.30 | 0.40 | 0.50 | 0.012 | 0.016 | 0.020 | |
| с | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.010 | |
| D | 5.20 BSC | | 0.205 BSC | | | | |
| D1 | 4.35 BSC | | | 0.171 BSC | | | |
| E | 5.55 BSC | | | 0.219 BSC | | | |
| E1 | 6.05 BSC | | | 0.238 BSC | | | |
| E2 | | 3.625 BSC 0.143 BSC | | | | | |
| E3 | 1.275 BSC | | | 0.050 BSC | | | |
| e | 1.27 BSC | | | 0.050 BSC | | | |
| L | 0.45 | 0.55 | 0.65 | 0.018 | 0.022 | 0.026 | |
| L1 | 0 | | 0.15 | 0 | | 0.006 | |
| L2 | 0.68 REF | | | 0.027 REF | | | |
| θ | 0° | | 10° | 0° | · · · · · · · | 10° | |